

Scanning Probe Microscopy for NanoElectronics

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Outline



1. High resolution structural imaging

- At lower forces
- At higher throughput

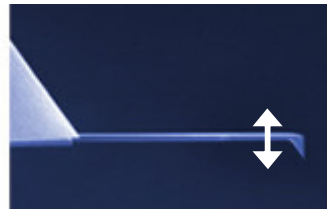
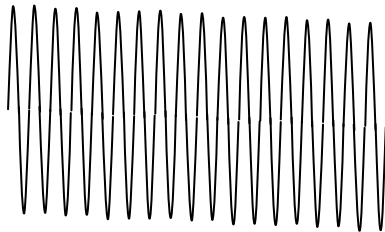
2. Property imaging:

- Mechanical characterization
- Electrical characterization
- Chemical characterization

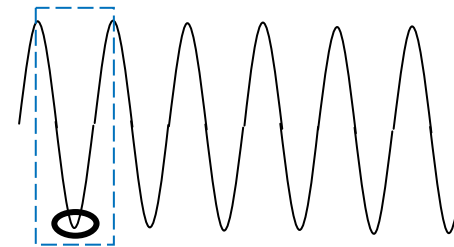
Lower Force Imaging using Peak Force Tapping



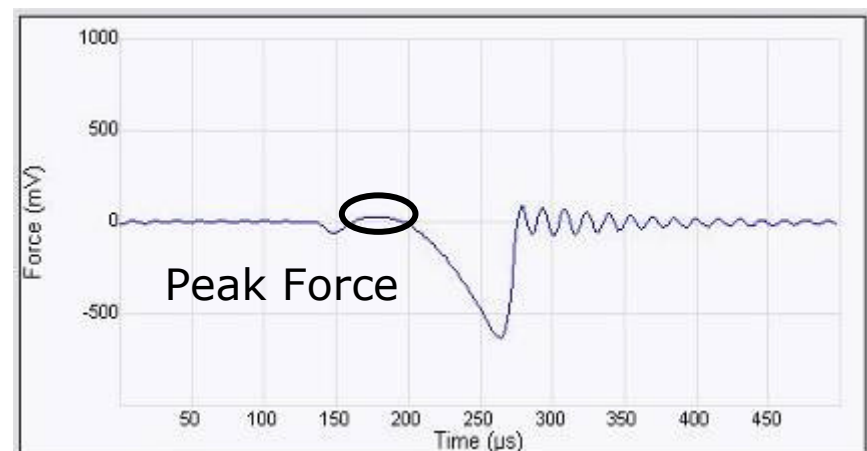
- Tapping:
 - Resonance (typ. 300kHz)
 - Measure & control Amplitude



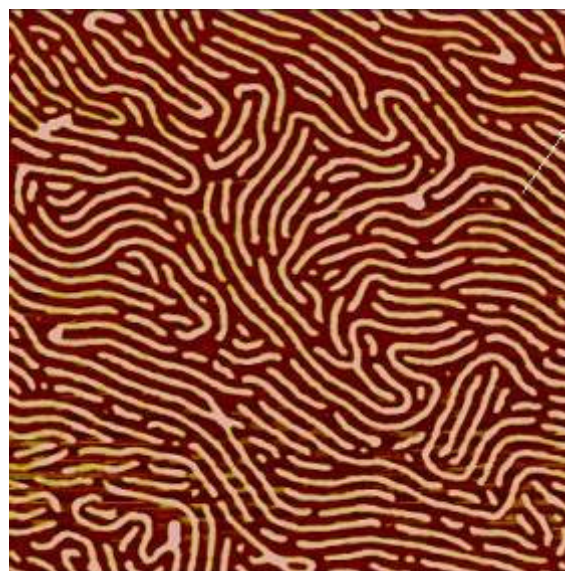
- Peak Force Tapping:
 - Sub-resonance (e.g. 2kHz)
 - Continuously measure the forces
 - Control the 'Peak Force'



- Result:
 - Lower force imaging ($< 50\text{pN}$)
 - Longer tip lifetime
 - Higher resolution

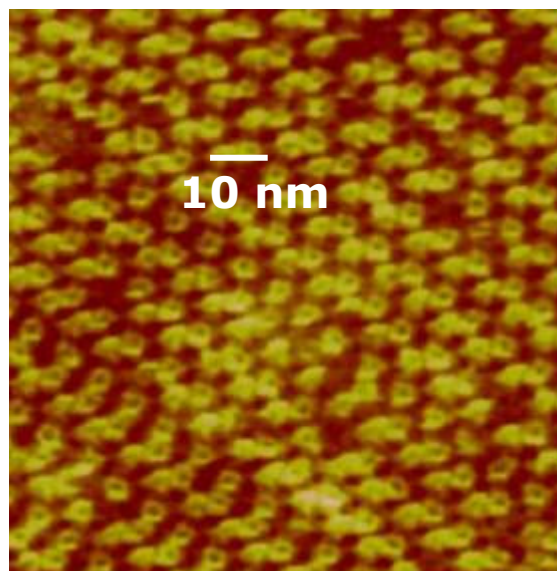


High Resolution Peak Force Tapping Examples



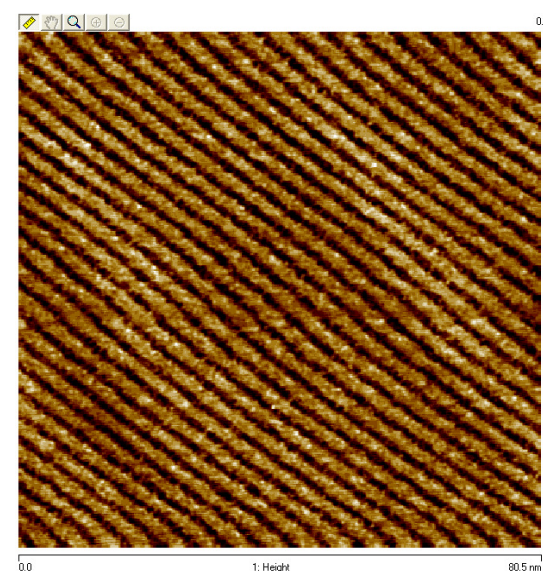
Self-Assembled
Molecular Brushes

1500x1500 nm scan



(OmpG Dimer)
Protein Membrane Pores

100x100 nm scan



C₁₈H₃₈
Alkane Molecules

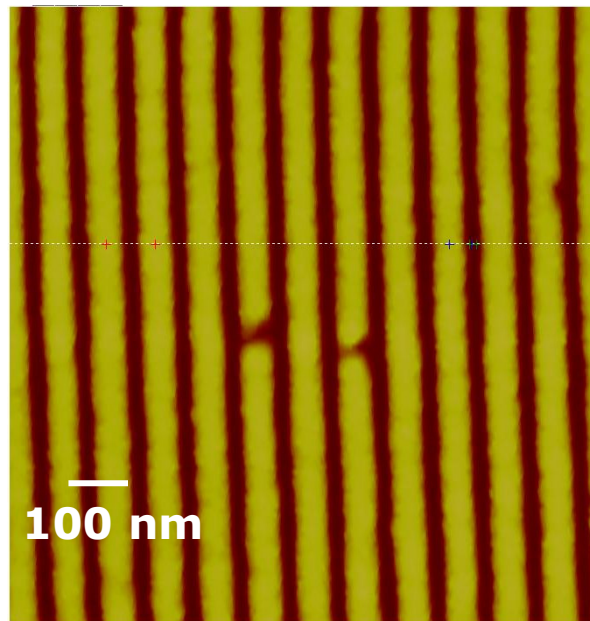
80x80 nm scan

Sample courtesy:
Ch. Bippes, MPI Dresden

Nanotrench Metrology using Peak Force Tapping

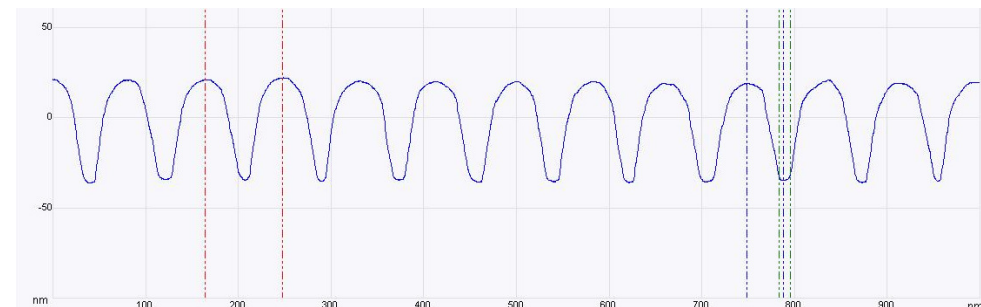
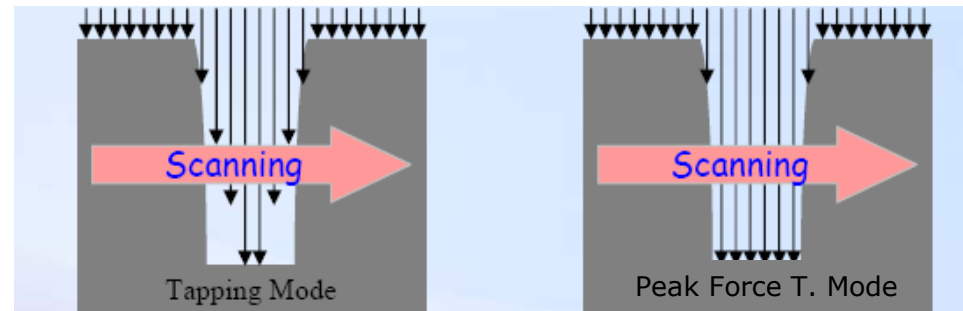


- Challenging in Tappingmode due to excessive damping of the probe oscillation, preventing the tip from reaching the bottom.
- Peak Force Tapping can more easily reach the bottom, while maximum force is tightly controlled to low values.



1000x1000 nm scan

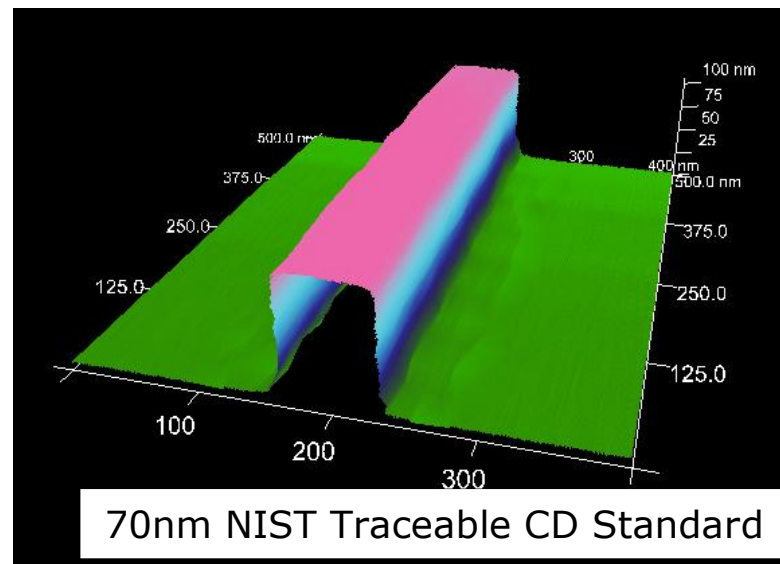
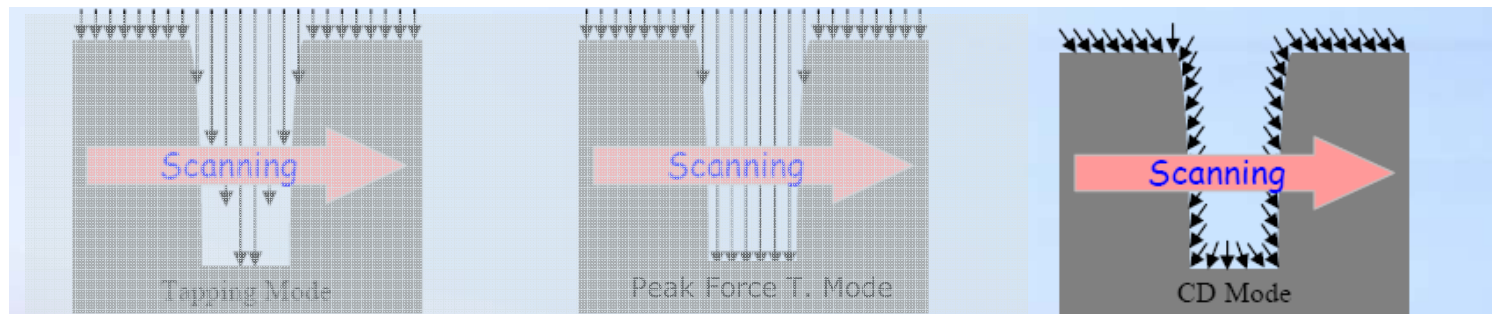
Pitch = 80 nm, Depth = 55 nm, Bottom travel = 13 nm



Critical Dimension (CD) Mode



- Scanner servos in X-Z or Y-Z direction
- Data is taken on sidewall as well as flat surface



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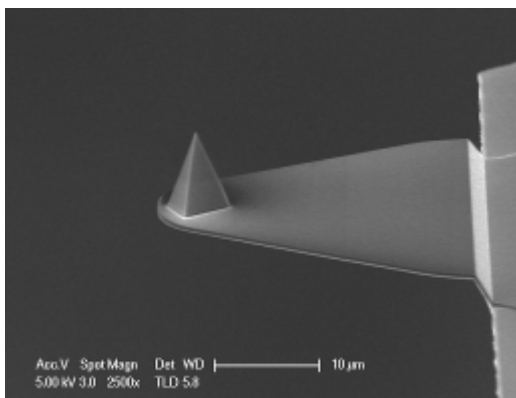
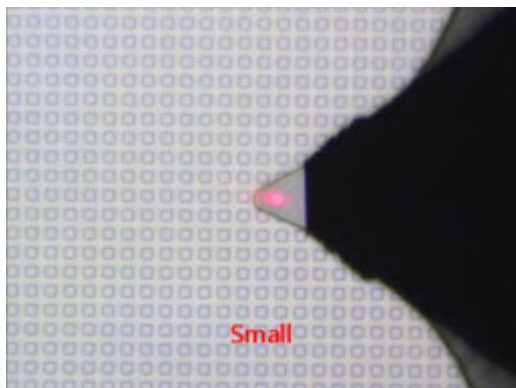
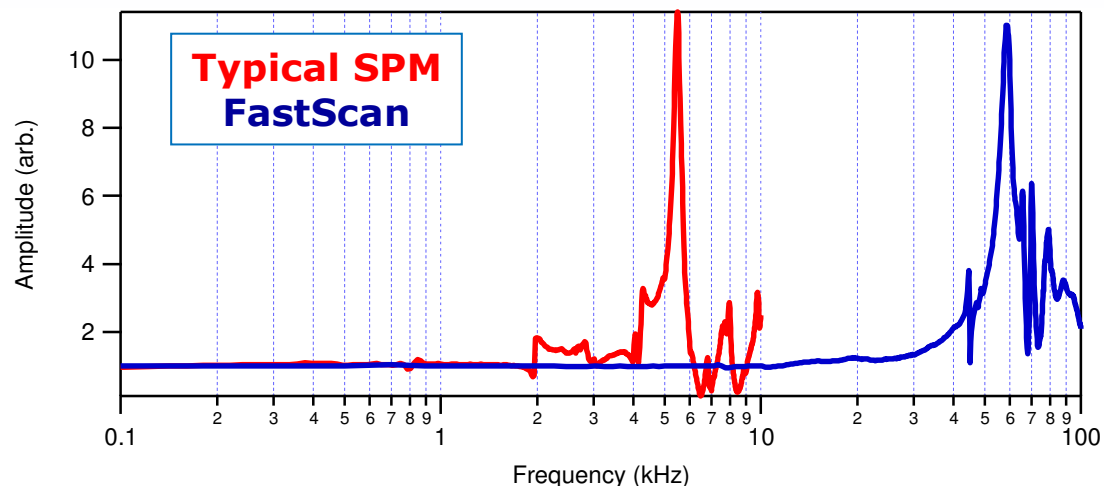
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- Electrical characterization
- Chemical characterization

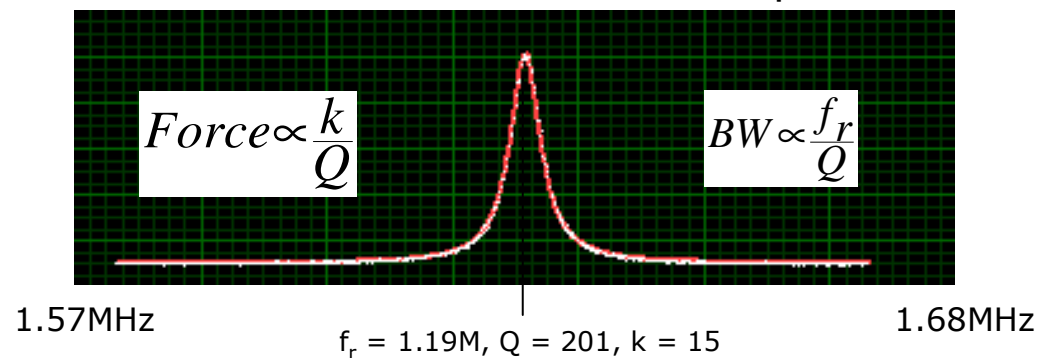
2 Elements limiting SPM speed: 'Z'-scanner & Tips



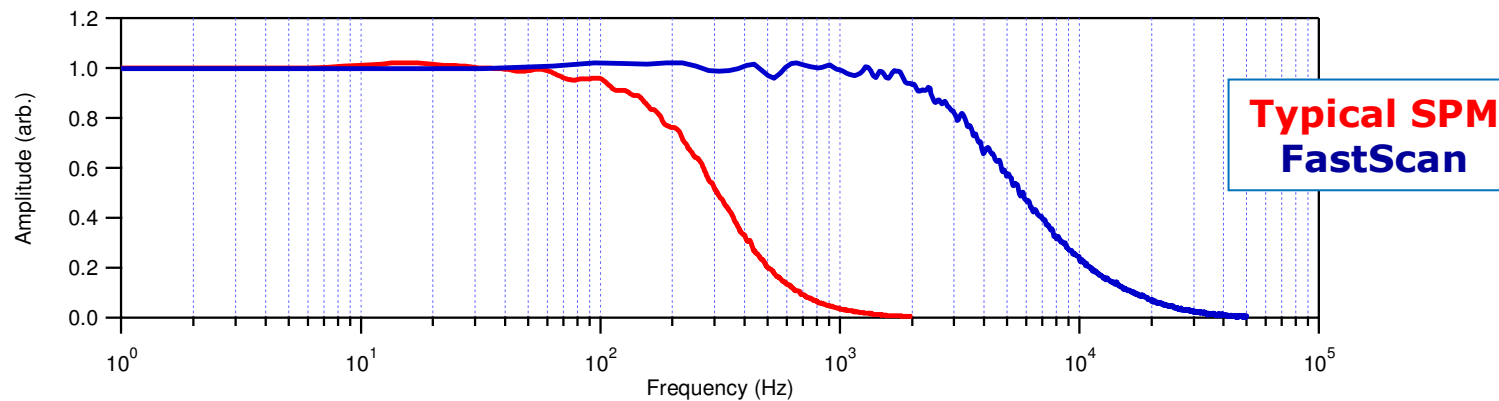
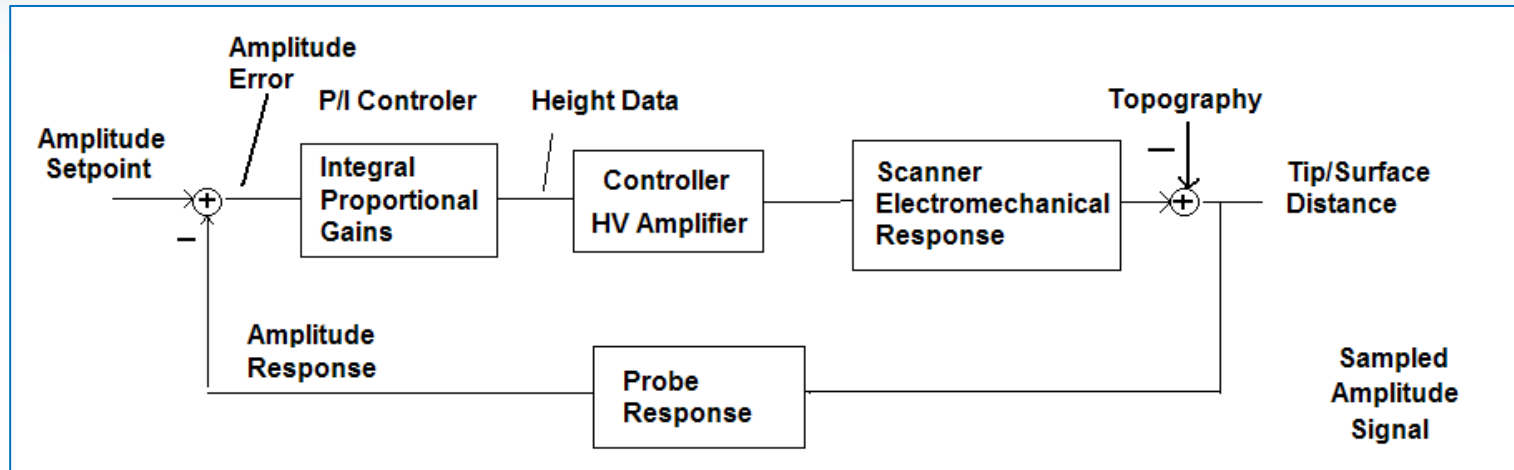
Z-Scanner Resonance > 55kHz



Small Cantilevers & Laser Spot



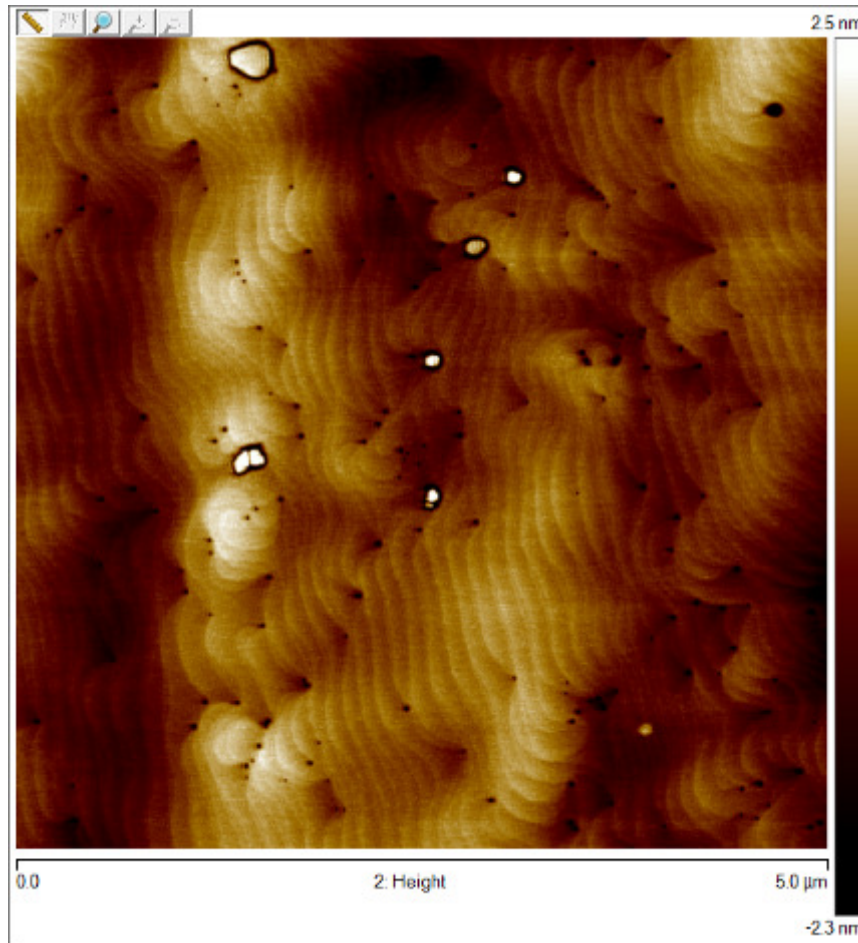
SPM System Transfer Function



- 20x increased bandwidth
- Same image quality, same force control

GaN on SiC

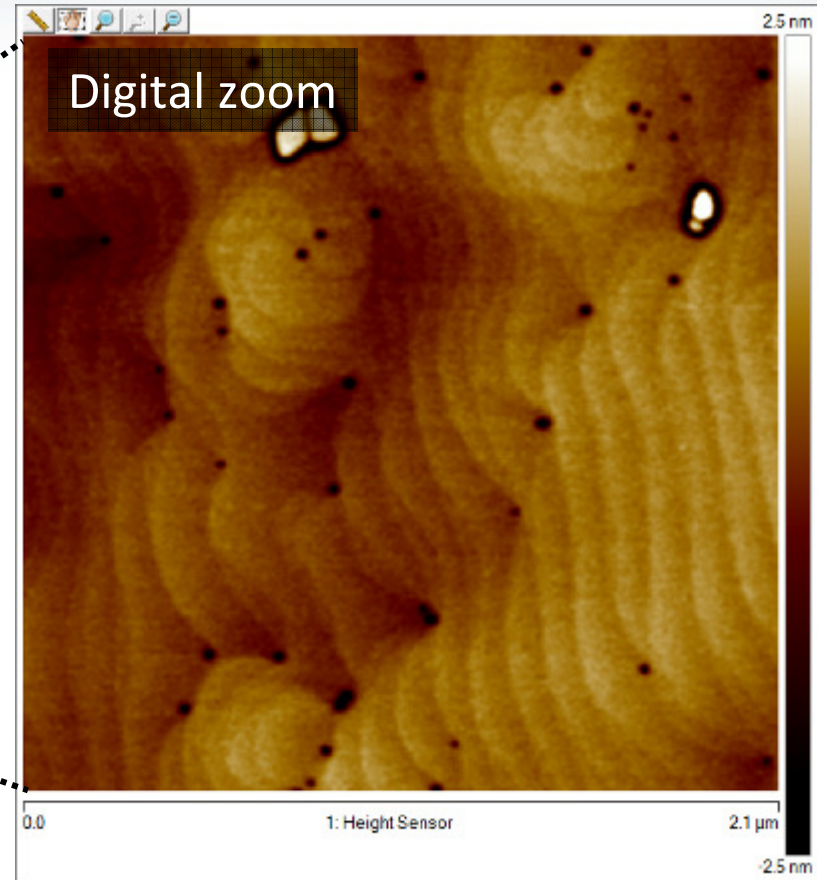
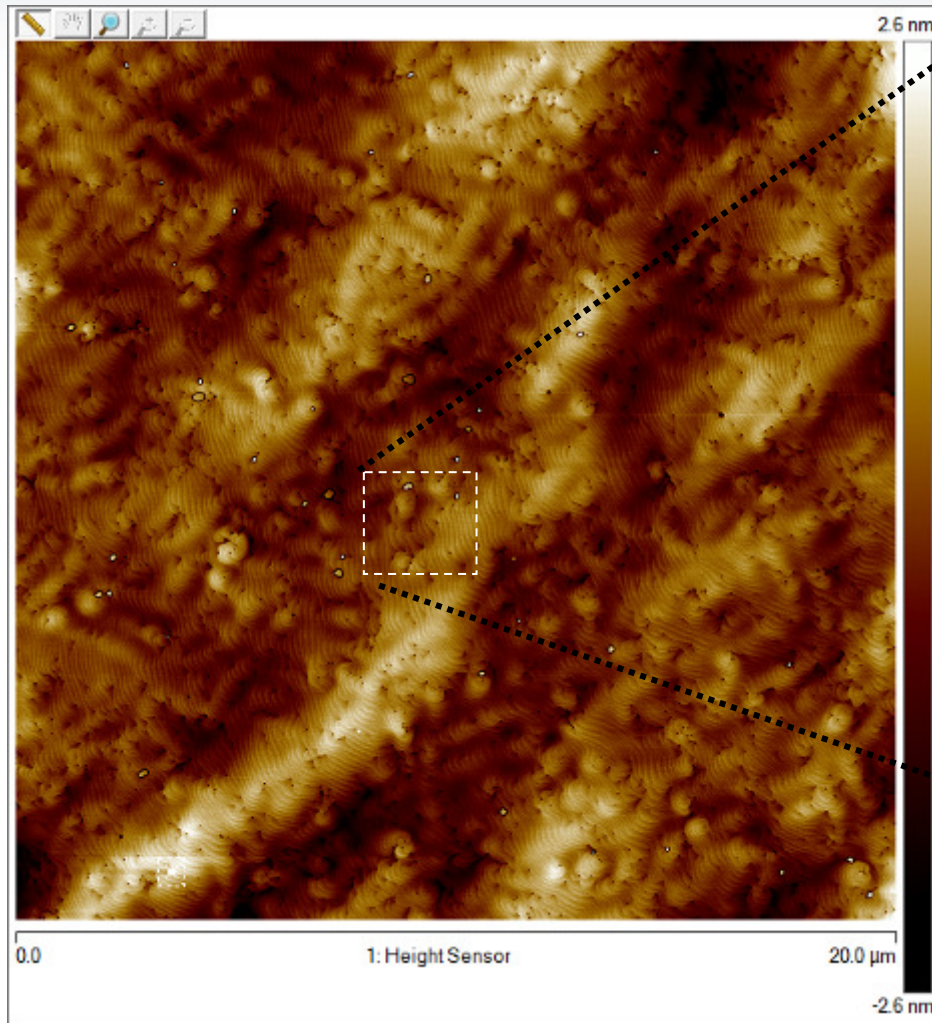
512x512 pixels, 38Hz Line Rate



- High-resolution image of:
- Edge & Screw dislocations
 - Atomic steps

13.5 seconds/image

GaN on SiC 4kx4k pixels, 10Hz Line Rate



6 min/image = typical image rate for traditional SPM, but now we have an image with 64x more pixels.

22Hz Line Rate on Poly-Si (512x512 pixels)

http://www.youtube.com/watch?v=I25zRZ2ng_E

2x2 μm scan, 25 Seconds per image

Dynamics: Molecular Studies (DNA in Fluid)

<http://www.youtube.com/watch?v=5cylVbEioIE>

Sample courtesy of Y. Lyubchenko, Univ. of Nebraska Med. Ctr.

1 second per image (2100 images)

Outline



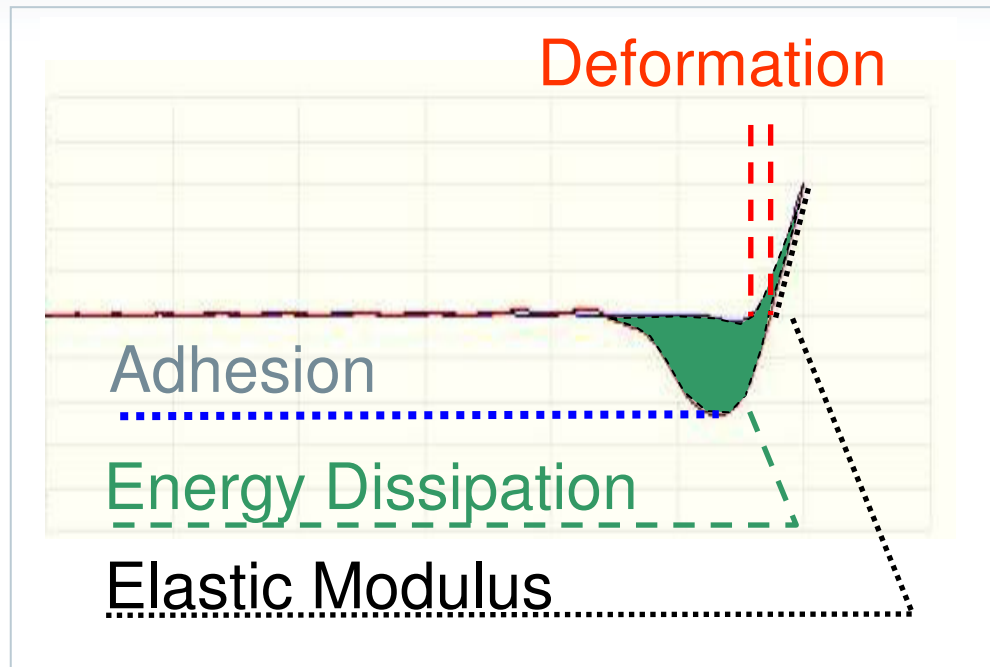
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2. Property imaging:

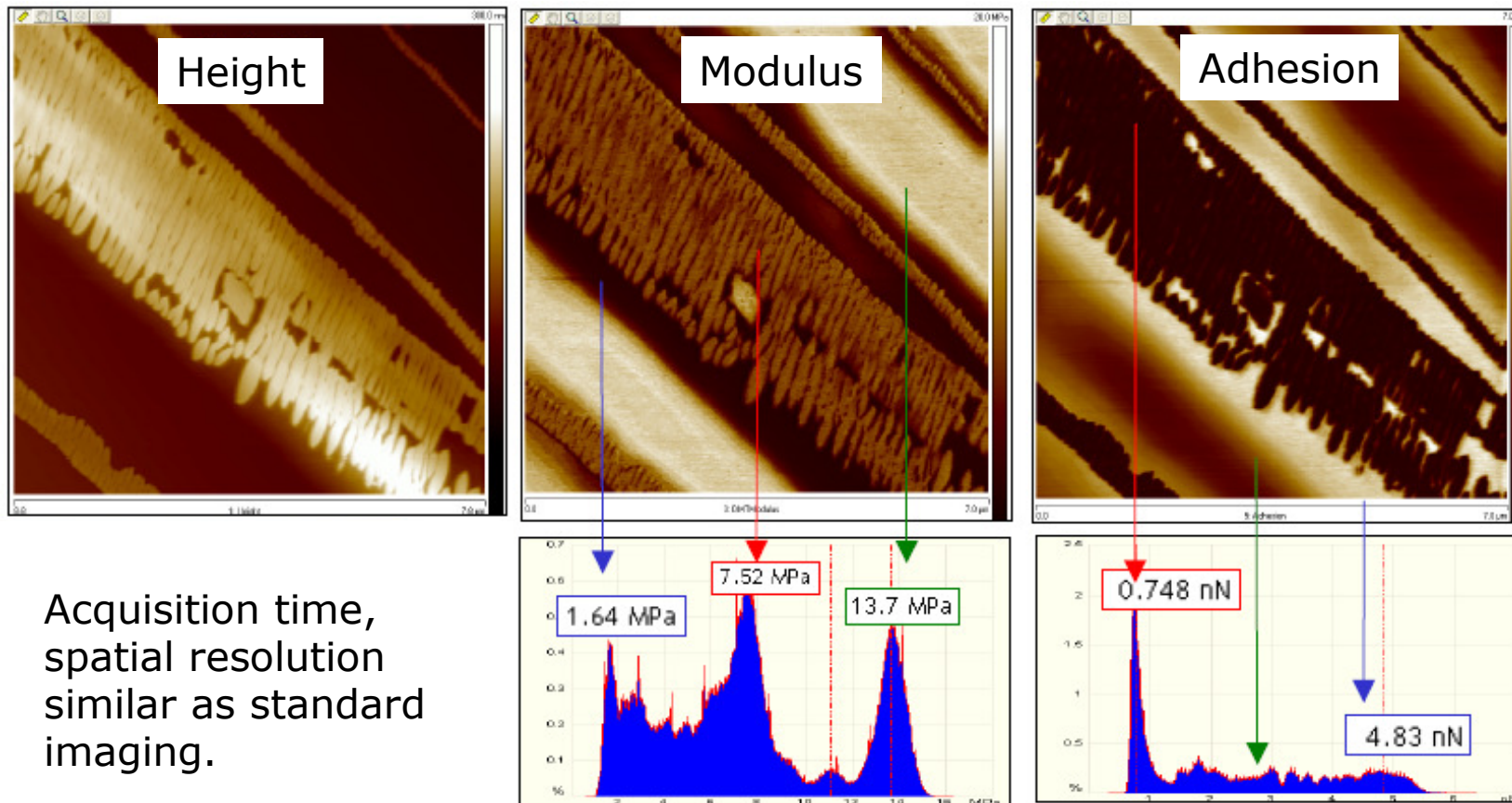
- Mechanical characterization
- Electrical characterization
- Chemical characterization

Quantitative Nanomechanical Mapping (QNM)



Modulus:	0.6 MPa-60 GPa
Energy dissipation:	1eV-tens keV
Adhesion:	10 pN ~ μ N
Deformation:	10 pm ~ 100 nm

QNM on Siloxane Liquid Crystal

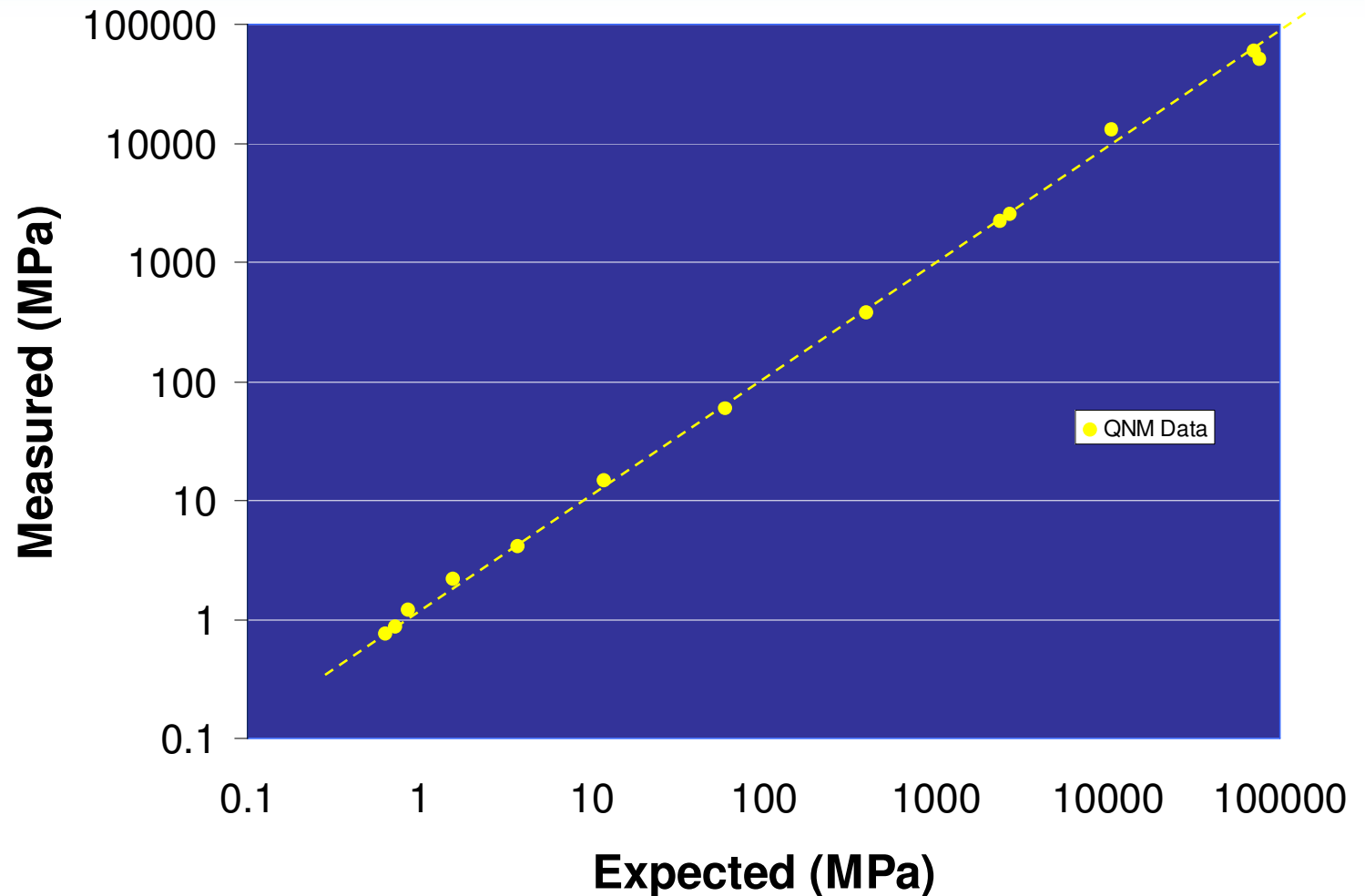


Acquisition time,
spatial resolution
similar as standard
imaging.

QNM on Benchmark Samples



Samples	Expec.	Meas.
DP150	0.63	0.76
DP130	0.73	0.87
DP110	0.86	1.2
DP60	1.58	2.2
DP25	3.78	4.1
DP8	11.8	14.5
LDPE90	60	58
LDPE93	400	370
SiLK	2400	2200
PS Film	2700	2500
HOPG	10500	12800
Au Foil	77200	50200
SiO2	71700	59400

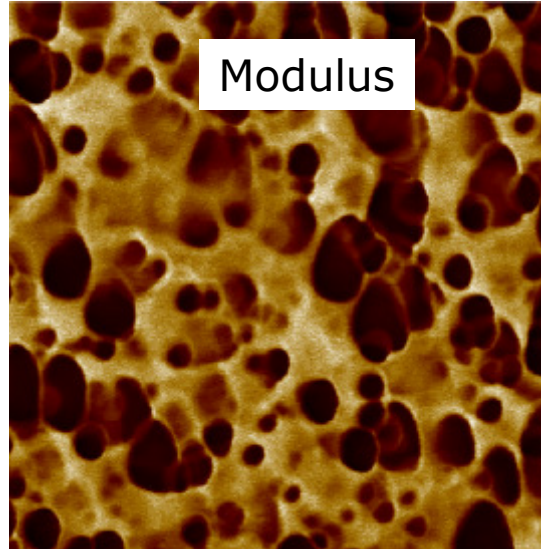
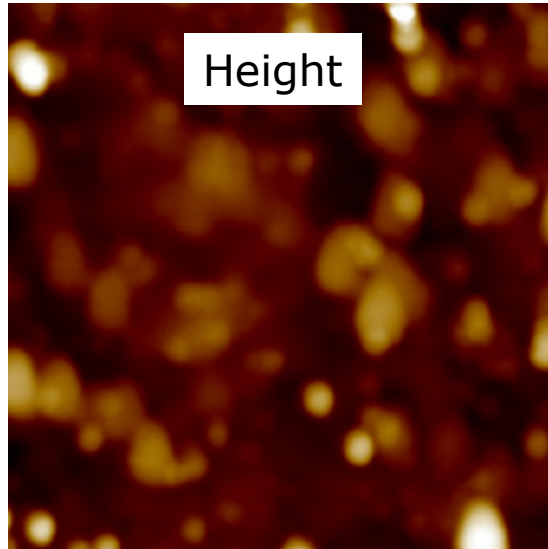
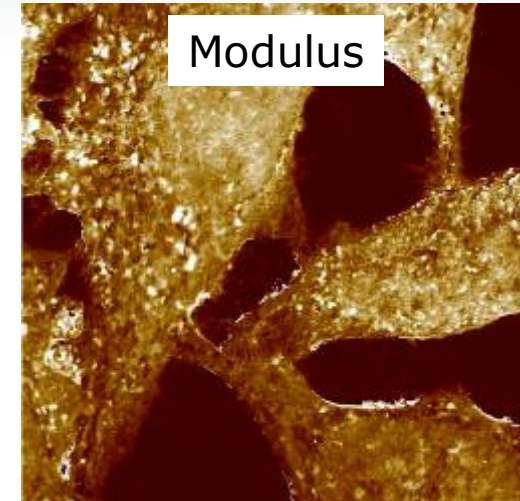
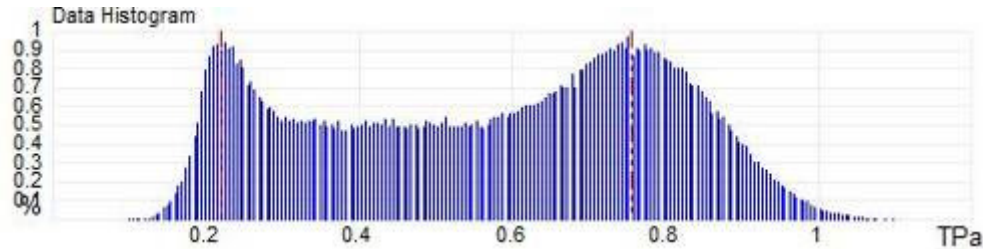


QNM on Very Hard & Very Soft Samples



10x10 μm scan size
WC / C sample
 $E \sim 650 / 50 \text{ GPa}$

80x80 μm scan size
HELA cells
 $E \sim 10\text{-}100\text{kPa}$



Electrical Characterization



- SPM-based electrical modes are often based on 'Contact mode' operation. The high vertical and lateral forces can cause:
 - Tip & sample damage
 - Limited reproducibility
 - Reduced resolution
 - Artifacts

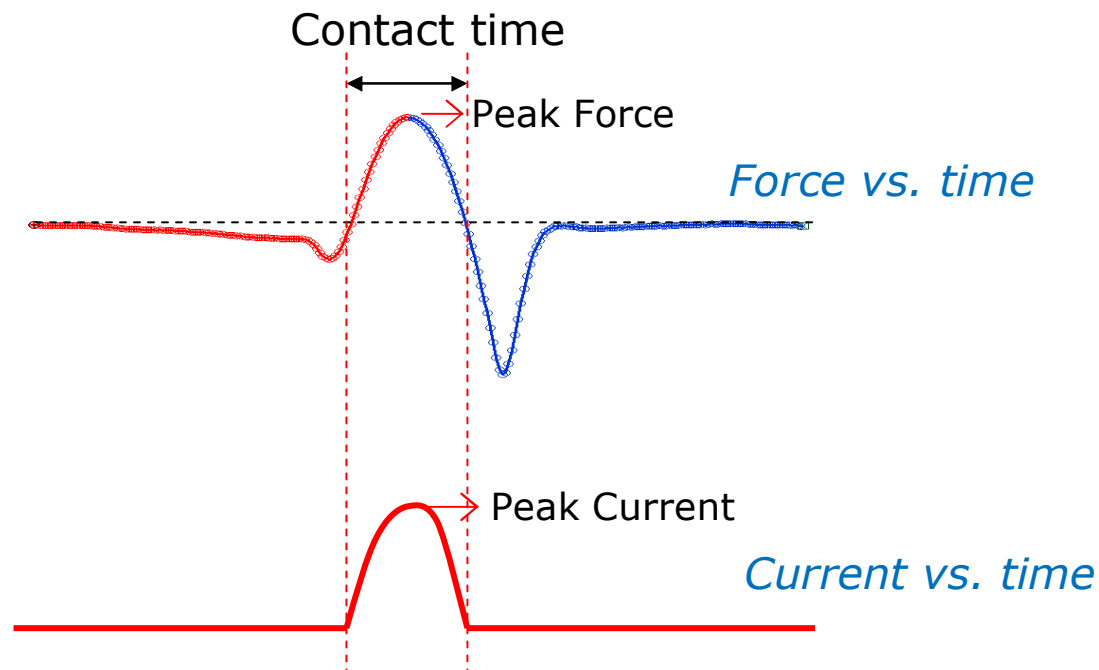
■ Solution?

	Force Levels	Contact Time
Tapping		
Peak Force Tapping		

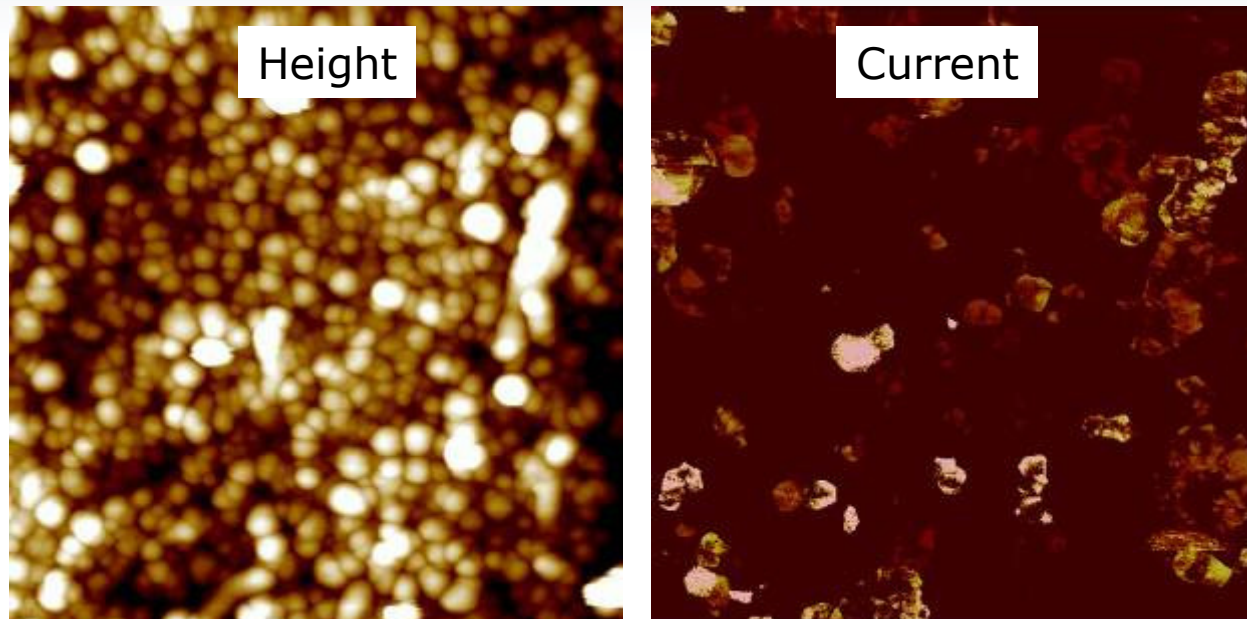
Combination of Peak Force Tapping / Conductive-AFM (or Tunneling-AFM)



- Tip oscillates at 1kHz. Contact time is typically 20 – 200 μ s.
- The average current during contact time & the peak current are measured.
- Requires fast C-AFM electronics: 20kHz bandwidth, <100fA noise



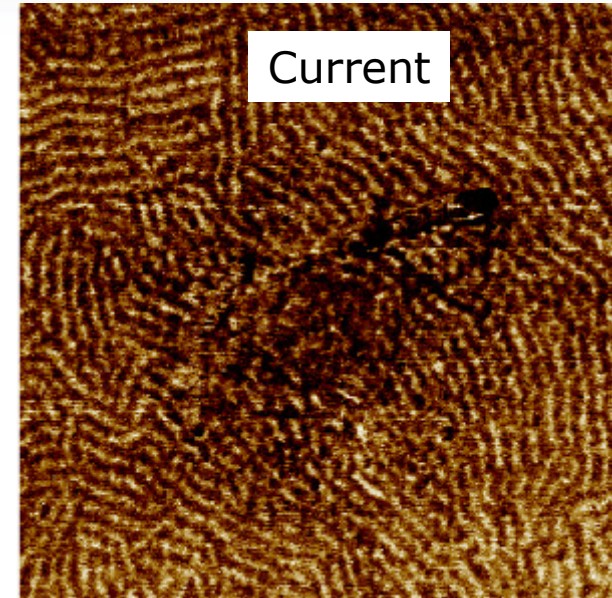
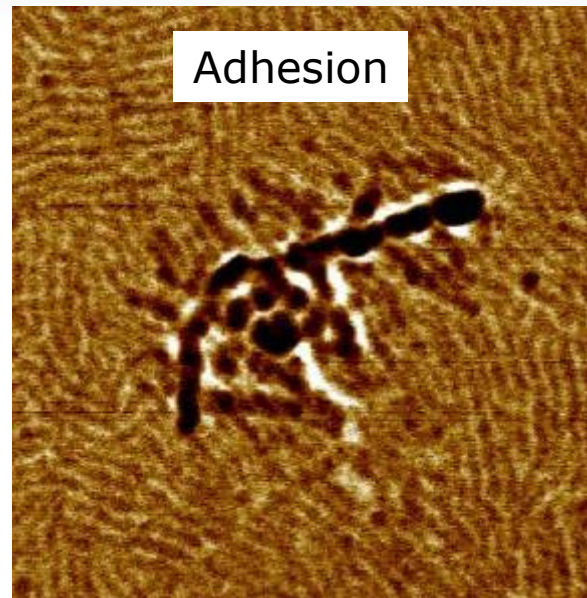
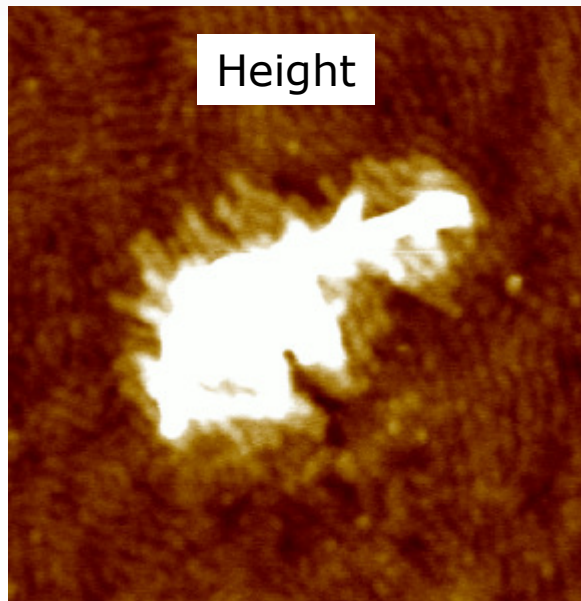
PF-TUNA Example: Carpet of standing Carbon Nanotubes



1000x1000 nm scan size

- Impossible in contact mode, as forces are too high.
- Reveals strong conductivity variations

PF-TUNA Example: Network of Conductive Polymer Macromolecules, around CNT



700x700 nm scan size

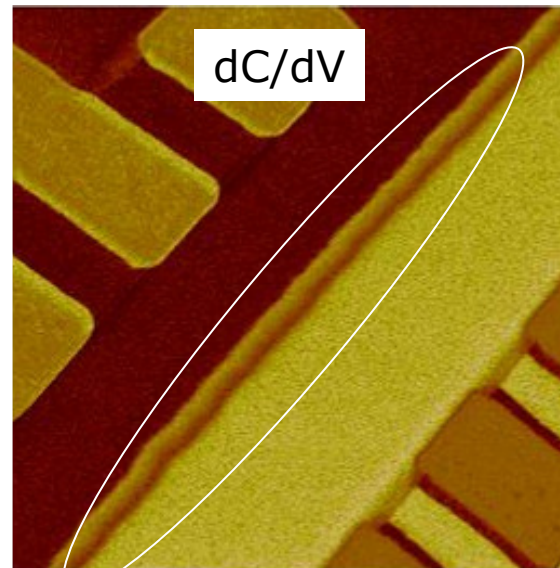
- Impossible in contact mode, as forces are too high.
- Higher resolution vs. contact mode.

Sample courtesy:
Ph. Leclere, Uni Mons (B)

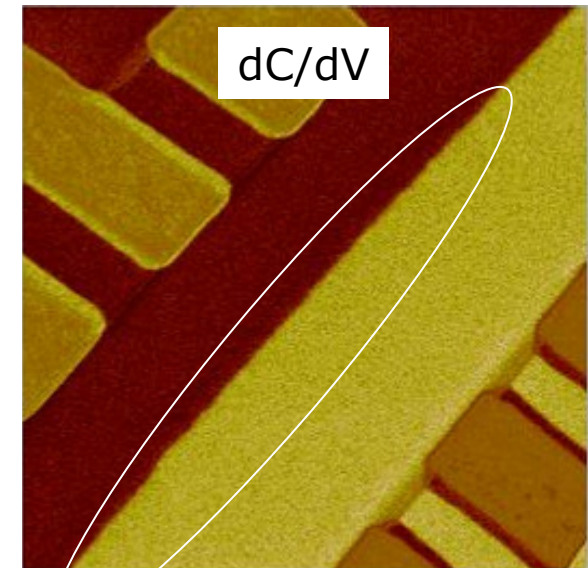
Eliminating the Effect of the AFM laser light



8x8 μm scan size



Laser on



Laser off

The surface is scanned twice:

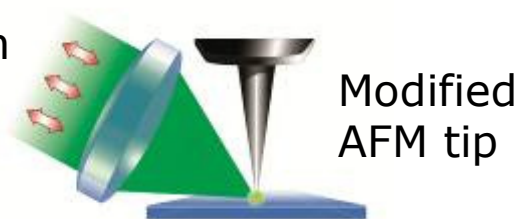
- 1) With laser light (measure topography)
- 2) Without laser light (measure artifact-free electrical info)

Chemical Characterization: TERS

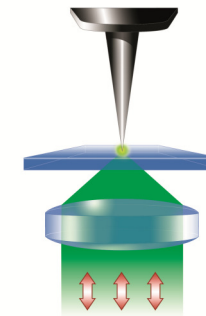


- Principle: Local field enhancement is achieved with a sharp metal structure that exhibits a surface plasmon resonance at the appropriate optical frequency, providing enhanced spatial resolution (Tip Enhanced Raman Spectroscopy)

Raman
optical path



Opaque samples:
tilted optical access



Transparent samples:
inverted optical access

Key Elements of the AFM-Raman



■ Probes:

- Forward pointing geometry
- Silicon Nitride base (avoids Raman background from Silicon)
- Coating of Ag (for excitation in blue or green), or Au (for excitation in red or NIR)

■ Optimized optical access:

- high numerical aperture (0.42 NA, 50x)
- off-axis optical access to the tip (30 degree tilt)



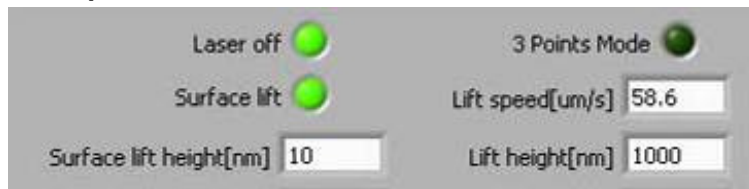
Key Elements of the AFM-Raman



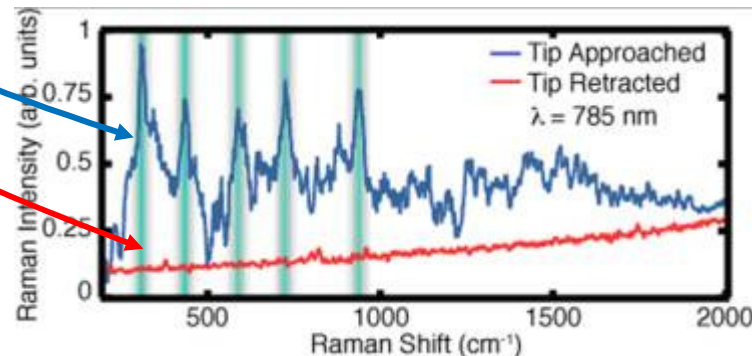
1. AFM & Raman control from central software:



3. "3 points mode" to test field enhancement:

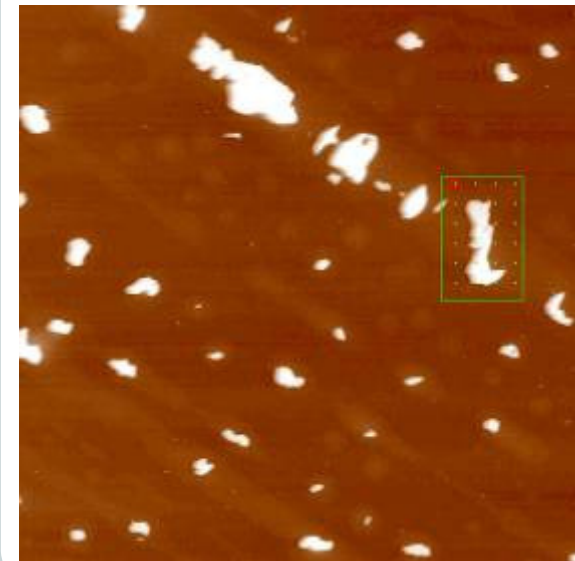


- Spectrum with tip on surface (i.e. near-field)
- Spectrum with tip off-surface (i.e. far-field or background)

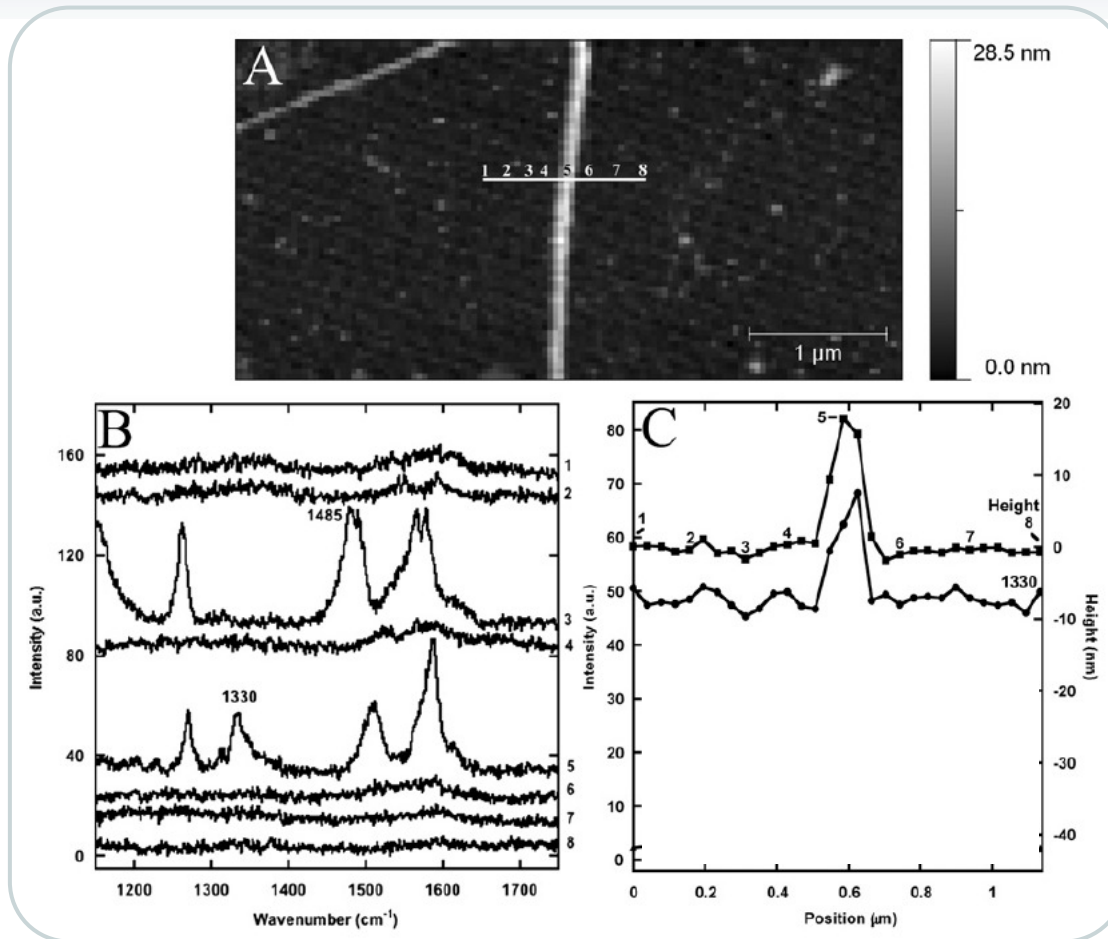


Courtesy:
M. Raschke,
U. Colorado

2. The AFM image is used to position the tip for Raman and/or TERS analysis.



TERS Example: Collagen I Fibrils



(A) AFM image with 1.1 μm path for TERS analysis.

(B) TERS spectra at different points along the path

(C) Height profile (squares) and the intensity of the 1330 peak (circles). FWHM = 100 nm.

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Acknowledgements



- Bruker Nano – Probes Division

- Sample & data courtesy:
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 - Ch. Bippes, MPI Dresden
 - Ph. Leclère, Uni Mons, Belgium

- Bruker Nano - Apps Team

